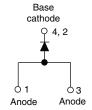


Vishay Semiconductors

Schottky Rectifier, 10 A





D-PAK (TO-252AA)

PRODUCT SUMMARY				
Package	D-PAK (TO-252AA)			
I _{F(AV)}	10 A			
V _R	45 V			
V _F at I _F	0.53 V			
I _{RM}	15 mA at 125 °C			
T _J max.	175 °C			
Diode variation	Single die			
E _{AS}	20 mJ			

FEATURES

- Popular D-PAK outline
- Small foot print, surface mountable



- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- \bullet Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C

DESCRIPTION

The VS-10WQ045FN surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform	10	A			
V _{RRM}		45	V			
I _{FSM}	t _p = 5 µs sine	400	Α			
V _F	10 Apk, T _J = 125 °C	0.53	V			
T _J	Range	- 40 to 175	°C			

VOLTAGE RATINGS					
PARAMETER SYMBOL VS-10WQ045FNPbF UNITS					
Maximum DC reverse voltage	V_{R}	45	V		
Maximum working peak reverse voltage	V_{RWM}	45	V		

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDI	VALUES	UNITS		
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 157 °C	10	А		
Maximum peak one cycle non-repetitive surge current	1	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	400	А	
See fig. 7	ge current I _{FSM} 10 ms sine or 6 ms rect. pulse rated V _{RRM} applied		75	A		
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 3 A, L = 4.4 mH		20	mJ	
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T_J maximum $V_A = 1.5 \times V_R$ typical		3.0	А	

VS-10WQ045FNPbF

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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS		
		10 A	T _{.1} = 25 °C	0.63	V	
Maximum forward voltage drop	V _{FM} ⁽¹⁾	20 A	1] = 23 0	0.80		
See fig. 1	VFM (*)	10 A	T _{.1} = 125 °C	0.53		
		20 A	1j = 125 C	0.71		
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	V _B = Rated V _B	1	- mA	
See fig. 2	'RM \"	T _J = 125 °C	VR = Hateu VR	15		
Threshold voltage	V _{F(TO)}	$T_J = T_J$ maximum		0.255	V	
Forward slope resistance	r _t			22	mΩ	
Typical junction capacitance	C _T	V _R = 5 V _{DC} (test signal range	760	pF		
Typical series inductance	L _S	Measured lead to lead 5 r	5.0	nH		

Note

 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,\,duty\,cycle < 2~\%$

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		- 40 to 175	°C	
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	2.0	°C/W	
Maximum thermal resistance, junction to ambient	R _{thJA}		50	C/VV	
Approximate weight			0.3	g	
Approximate weight			0.01	OZ.	
Marking device		Case style D-PAK (similar to TO-252AA)	10WQ	045FN	

Note

$$^{(1)} \quad \frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}} \quad \text{thermal runaway condition for a diode on its own heatsink}$$



Schottky Rectifier, 10 A

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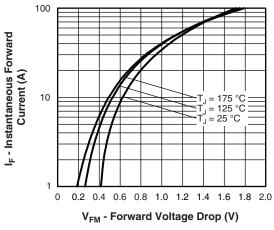


Fig. 1 - Maximum Forward Voltage Drop Characteristics

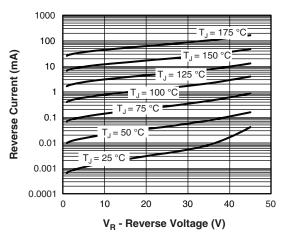


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

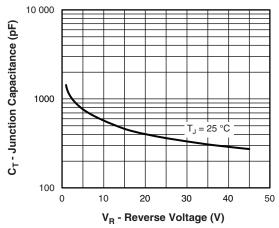


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

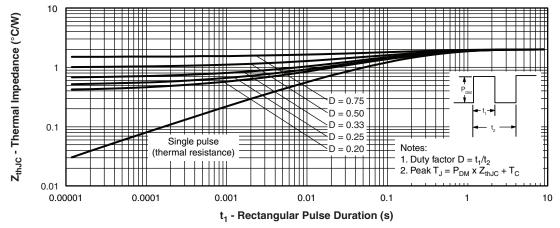


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

Vishay Semiconductors

Schottky Rectifier, 10 A



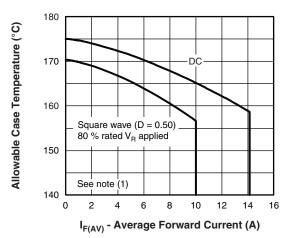


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

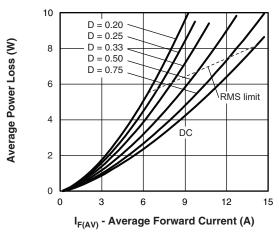


Fig. 6 - Forward Power Loss Characteristics

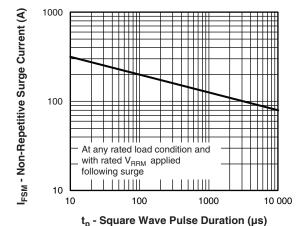


Fig. 7 - Maximum Non-Repetitive Surge Current

Note

(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}$; $Pd = Forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = Inverse power loss = V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = 80 \%$ rated V_R

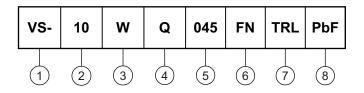


Schottky Rectifier, 10 A

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (10 A)

3 - Package identifier:

W = D-PAK

4 - Schottky "Q" series

5 - Voltage rating (045 = 45 V)

- FN = TO-252AA (D-PAK)

7 - • None = Tube (50 pieces)

• TR = Tape and reel

• TRL = Tape and reel (left oriented)

• TRR = Tape and reel (right oriented)

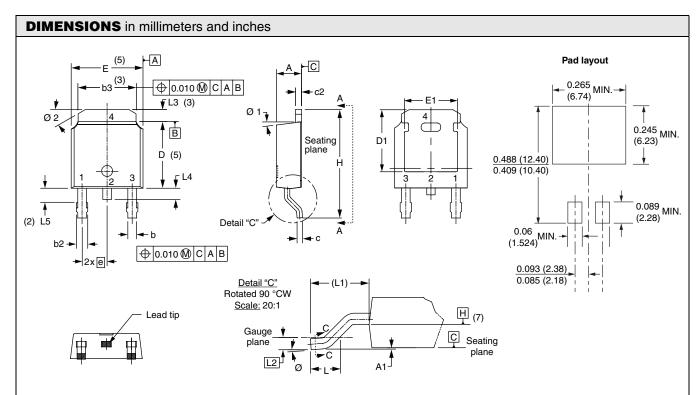
8 - PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?95016</u>				
Part marking information	www.vishay.com/doc?95059			
Packaging information	www.vishay.com/doc?95033			



Vishay High Power Products

D-PAK (TO-252AA)



SYMBOL	MILLIM	ETERS	INC	NOTES	
STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	2.18	2.39	0.086	0.094	
A1	-	0.13	-	0.005	
b	0.64	0.89	0.025	0.035	
b2	0.76	1.14	0.030	0.045	
b3	4.95	5.46	0.195	0.215	3
С	0.46	0.61	0.018	0.024	
c2	0.46	0.89	0.018	0.035	
D	5.97	6.22	0.235	0.245	5
D1	5.21	-	0.205	-	3
Е	6.35	6.73	0.250	0.265	5
E1	4.32	-	0.170	-	3

SYMBOL	MILLIMETERS		INCHES		NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
е	2.29	BSC	0.090	BSC	
Н	9.40	10.41	0.370	0.410	
L	1.40	1.78	0.055	0.070	
L1	2.74 BSC		0.108 REF.		
L2	0.51	BSC	0.020	BSC	
L3	0.89	1.27	0.035	0.050	3
L4	-	1.02	-	0.040	
L5	1.14	1.52	0.045	0.060	2
Ø	0°	10°	0°	10°	
Ø1	0°	15°	0°	15°	
Ø2	25°	35°	25°	35°	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L5
- (3) Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- (4) Section C C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- (5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (6) Dimension b1 and c1 applied to base metal only
- $^{(7)}$ Datum A and B to be determined at datum plane H
- (8) Outline conforms to JEDEC outline TO-252AA





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